

**Single Event Radiation Hardened
High Speed, Current Mode PWM**



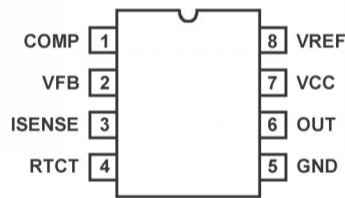
The IS-1845ASRH is designed to be used in switching power supplies operating in current-mode. The rising edge of the on-chip oscillator turns on the output. Turn-off is controlled by the current sense comparator and occurs when the sensed current reaches a peak controlled by the error amplifier. The error amplifier output is the difference between the sampled voltage and V_{REF} .

Constructed with Intersil's Rad Hard Silicon Gate (RSG) dielectrically isolated BiCMOS process, these devices are immune to single event latch-up and have been specifically designed to provide a high level of immunity to single event transients. All specified parameters are guaranteed and tested for 300krad(Si) total dose performance.

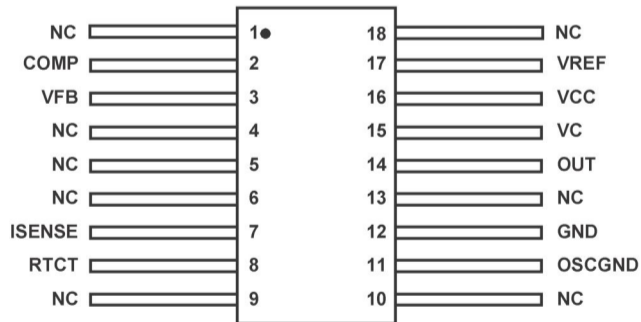
Detailed Electrical Specifications for these devices are contained in SMD 5962-01509. A "hot-link" is provided on our homepage for downloading the SMD. www.intersil.com/spacedefense/spacenevprod.asp

Pinout

IS7-1845ASRH (CDIP2-T8 SBDIP)
TOP VIEW



IS9-1845ASRH (FLATPACK)
TOP VIEW



NOTE: Grounding the Comp pin does not inhibit the output. The output may be inhibited by applying >1.2V to the ISENSE pin.

Features

- Electrically Screened to DSCC SMD # 5962-01509
- QML Qualified per MIL-PRF-38535 Requirements
- Radiation Environment
 - Total Dose 300 krad(Si) (Max)
 - SEL Immune Dielectrically Isolated
 - SEU Immune 35MeV/mg/cm²
 - SEU Cross-Section at 89MeV/mg/cm² 5 x 10⁻⁶cm²
- Low Start-up Current 100µA (Typ)
- Fast Propagational Delay 80ns (Typ)
- Supply Voltage Range 12V to 20V
- High Output Drive 1A (Peak, Typ)
- Under Voltage Lockout . . 8.8V Start (Typ), 8.2V Stop (Typ)
- 2.5V Voltage Reference (VREF)
- Switching Frequencies to 500kHz

Applications

- Current-Mode Switching Power Supplies
- Control of High Current FET Drivers
- Motor Speed and Direction Control

Ordering Information

ORDERING NUMBER	INTERNAL MKT. NUMBER	TEMP. RANGE (°C)
5962F0150901VPC	IS7-1845ASRH-Q	-50 to 125
5962F0150901QPC	IS7-1845ASRH-8	-50 to 125
5962F0150901VXC	IS9-1845ASRH-Q	-50 to 125
5962F0150901QXC	IS9-1845ASRH-8	-50 to 125
IS7-1845ASRH/Proto	IS1-1845ASRH/Proto	-50 to 125
IS9-1845ASRH/Proto	IS9-1845ASRH/Proto	-50 to 125

IS-1845ASRH

Die Characteristics

DIE DIMENSIONS

3090 μm x 4080 μm (121.6 mils x 159.0 mils)
 Thickness: 483 μm \pm 25.4 μm (19 mils \pm 1 mil)

INTERFACE MATERIALS

Glassivation

Type: Phosphorus Silicon Glass (PSG)
 Thickness: 8.0kA \pm 1.0kA

Top Metallization

Type: AlSiCu
 Thickness: 16.0kA \pm 2kA

Substrate

Radiation Hardened Silicon Gate,
 Dielectric Isolation

Backside Finish

Silicon

ASSEMBLY RELATED INFORMATION

Substrate Potential

Unbiased (DI)

ADDITIONAL INFORMATION

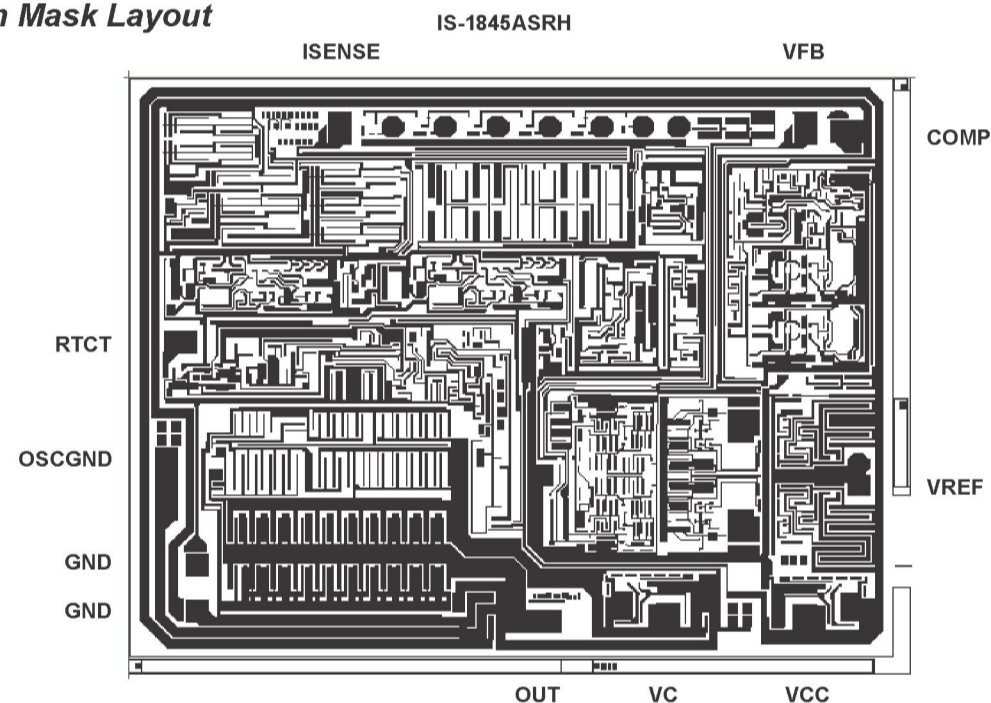
Worst Case Current Density

$< 2.0 \times 10^5 \text{ A/cm}^2$

Transistor Count

582

Metallization Mask Layout



NOTES:

1. Both the GND pads must be bonded to ground.
2. The OUT double-sized bond pad must be double bonded for current sharing purposes.
3. The OSCGND double-sized bond pad must be double bonded to ground for current sharing purposes.

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